**深圳市强生光电科技有限公司**

###### Shenzhen JNJ Optoelectronics Co.,Limited

产品规格书

**SPECIFICATION FOR APPROVAL**

|  |  |
| --- | --- |
| **客户名称****Customer** |  |
| **样品名称****Description** | **3036 20MIL 850NM 30度** |
| **产品型号****Part No** | **JNJ-LTJI0108W30/20mil** |
| **制作日期****Date** | **2019-07-15** |

|  |  |  |  |
| --- | --- | --- | --- |
| **制作****Producer** | **工程部****Engineering Dept.** | **业务部****Business department** | **批准****Approval** |
|  |  |  |  |

|  |
| --- |
| **客户承认结果****Customer acknowledges Results** |
|  |  |  |

**外观Exterior：**



**产品构造Product conformation：**

## ■ 封装胶水：无色透明硅胶

Packaging glue: colorless transparent silica gel

■ 封装支架：3036支架

Packaging bracket:3036 holder

■ 发光颜色：红外(不可见光) 波长850nm

Luminous color: Infrared (invisible light) wavelength 850nm

■ 芯片规格：晶元20mil\*20mil

Chip specification:jing yuan 20mil\*20mil

■ 发光角度：30度

Luminous Angle: 30 degrees

■ 静电敏感材质

Electrostatic sensitive material



**应用Applications：**

■ 红外应用系统infrared applications systems

■ 红外相机infrared lllumination for cameras

■ 安防监控 secunrity monitoring

■ 无线通讯wireless communication

**产品外形尺寸Package outline dimensions：**

****

****

****

 焊盘建议大小Recommended size of pad

**焊点结构Pad Configuration：**

|  |  |
| --- | --- |
| 焊点Pad | 功能Function |
| 1 | 正极Anode |
| 2 | 负极Cathode |

备注(Note)：

1. 标注尺寸单位为毫米

Dimensions are in millimeters.

1. 除特别标注外，所有尺寸允许公差± 0.1mm .

Tolerances unless mentioned are ± 0.1mm.

**极限参数 AbsoluteMaximumRatingsat：**

|  |  |  |  |  |
| --- | --- | --- | --- | --- |
| 电气特性Electrical characteristics | 符号Symbol | 额定值Rated Value | 单位Unit | 环境温condition Temperature |
| 最大持续工作电流Max continuous working current | IF | ≤350 | mA | Ta=25°C |
| 最大脉冲工作电流\*Max pulse current | IFP | 2 | A | Ta=25°C |
| 反向电压Reverse breakdown voltage | VR | 10 | V | Ta=25°C |
| 工作温度Operating Temperature | Topr | -25℃ to +85℃ | °C |  |
| 存储温度Storage Temperature | Tstg | 0℃ to +40℃ | °C |  |
| 回流焊温度Circle solder Temperature | Tsol | 245℃ for 10sec | °C |  |
| 结温complete Temperature | Tj | 115 | °C |  |

**光性能特点OpticalCharacteristics：**

|  |  |  |  |  |  |  |
| --- | --- | --- | --- | --- | --- | --- |
| 参数Parameter | 符号Symbol | 测试条件 | 最小Min | 平均Typ | 最大Max | 单位Unit |
| 光功率Luminous power | Po | IF=50mA | 30 |  |  | mW |
| IF=350mA | 150 |  |  |
| 光强Luminous intensity | Ie | IF=50mA | 35 | 45 | 70 | mW/Sr |
| IF=350mA | 380 | 530 | 650 |
| 视角Emission Angle | 2θ1/2 |  |  | 30 |  | Deg |
| 波长Wavelength | λp | IF=350mA | 840 | 850 | 870 | nm |
| 半波宽Half wave width | Δλ | IF=350mA |  | 45 |  | nm |
| 正向电压Forward Voltage | VF | IF=50mA | 1.3 | - | 2.0 | V |
| IF=350mA | 1.4 | - | 2.1 |
| 反向电流Reverse current | IR | VR=5.0V | - |  | 10 | μA |

备注(Note)：

1. θ1/2 是半值角，指辐射强度是光学中心线光强的 1/2 到光学中心线的角度

Theta 1/2 is the half-value Angle, which refers to the Angle of radiation intensity from the optical center line to the optical center line, which is 1/2 of the light intensity of the optical center line

1. 上述辐射通量的测试允许公差是±10%

The permissible tolerance for the above radiation flux test is±10%

1. 以上所示电压测量误差±0.1v

The voltage measurement error shown above is ±0.1v

1. 以上所示波长测量误差±1nm

The above wavelength measurement error is ±1nm

**LED 芯片特性曲线Typical Electro-Optical Characteristics Curves：**

**LED光强分布曲线(50mA测试)** **Intensity distribution curve (50mA test)：**

**信赖性测试项目及条件ReliabilityTest：**

|  |  |  |  |  |  |
| --- | --- | --- | --- | --- | --- |
| 测试项目Test Parameter | 参考标准Reference Criterion | 测试条件Test Condition | 时间Time | 数量Quantity | 接受/拒收Ac/Re |
| 回流焊Resistance to Soldering Heat | JESD22-B106 | Temp:245℃max T=10sec | 3 times | 22Pcs | 0/1 |
| 温度循环thermocycling | JESD22-A104 | 100℃±5℃30min.-40℃±5℃30min. | 100 Cycles | 22Pcs | 0/1 |
| 高温保存High Temperature storage | JESD22-A103 | Temp:100℃±5℃ | 1000Hrs | 22Pcs | 0/1 |
| 低温保存Low Temperature storage | JESD22-A119 | Temp:-40℃±5℃ | 1000Hrs | 22Pcs | 0/1 |
| 常温通电Operating Life Test | JESD22-A108 | Ta=25℃±5℃IF=350mA | 1000Hrs | 22Pcs | 0/1 |
| 高温高湿通电High Temperature High Humidity | JESD22-A101 | 85℃±5℃/85％RHIF=350mA | 1000Hrs | 22Pcs | 0/1 |

**失效判定标准****Judgement standard fail**

|  |  |  |  |
| --- | --- | --- | --- |
| 项目Parameter | 符号Symbol | 测试条件Test Condition | 判定标准Judgement standard |
| 最小Min | 最大Max |
| 正向电压Forward Voltage | VF | IF=350mA | -- | U.S.L\*）×1.2 |
| 反向电流Reverse current | IR | VR=10V | -- | U.S.L\*）×2.0 |
| 辐射强度Luminous intensity | mW/sr | IF=350mA | L.S.L\*）×0.7 | -- |

备注(Note)：

1. U.S.L：规格上限；L.S.L 规格下限
2. 数据表格中所示的技术信息仅限于典型特征值和电路实例引用的产品，它既不构成工业特性的保证，也不构成任何许可的授权

The technical information shown in the data table is limited to products referenced by typical eigenvalues and circuit instances and does not constitute a guarantee of industrial characteristics nor does it constitute an authorization of any license

**卷轴尺寸Reel Dimensions：**

****

**使用方向及尺寸Progressive direction and Dimensions:**

****

**产品包装及外标签Moisture Resistant Packaging**：



**标签规格Label Form Specification：**

****

**LED 应用注意事项Application precautions:**

**保存及使用Preservation and use:**

1. 在打开包装前，LED 应存放在 30℃/60%RH 或以下的环境中。打开包装后，LED 应置于 20-30℃/30%RH 或以下的环境中使用。

Before opening the package, the LED should be stored at 30℃/60%RH or less.After opening the package, the LED should be placed in an environment of 20-30℃/30%RH or less.

1. molding 封装及 SMD LED 开封后要在 24H 之内使用，为了避免环境的影响，建议拆封后，经 过 60℃/24H 除湿，没用完 LED 需及时做抽真空包装处理，避免再次使用时发生失效。

To avoid the impact of the environment, it is recommended to dehumidify after unpacking at 60℃/24H. All the leds are needed to be vacuumed to avoid failure

1. 若干燥剂褪色或过期使用，需干燥烘烤：60±5℃/24 小时。

If the desiccant faded or expired use, dry baking: 60±5℃/24 hours.

1. LED 的胶表面易沾灰尘，需要做好相关防尘措施。

LED Glue surface easy to dust, need to do the relevant dust prevention measures.

### 取放pick and place

夹取 LED 时只能触及支架体，镊子之类的工具不要对透镜施压。更不要刺或推透镜。

When taking the LED, you should only touch the bracket. Tools such as tweezers should not put pressure on the lens.Don't stab or push the lens.

### 热量处理Heat treatment

在过大电流驱动时 LED 的 Tj（节点温度）会超过期限制值，这导致 LED 的寿命严重缩短，热量 处理措施要有效的减小应用产品的热阻。比较通用的做法：把 LED 封装器件安装在金属基质的 PCB 板上。1W LED 产品要求金属基板的表 面散热面积至少 30cm²（3W 产品建议 80cm²以上），且其导热系数要高于 2.0W/mK。LED 和金 属基板结合靠导热性较好的导热胶，要求导热系数高于 1.0W/mK，厚度小于 100um。

When driven by excessive current, the Tj (node temperature) of LED will exceed the period limit value, which leads to a serious shortening of LED life. Thermal treatment measures should effectively reduce the thermal resistance of application products.Common practice: install LED packages on metal matrix PCB boards.1W LED products require the surface heat dissipation area of the metal substrate to be at least 30cm squared (over 80cm squared is recommended for 3W products), and its thermal conductivity is higher than 2.0w /mK.LED and gold substrate are combined by thermal conductive adhesive with good thermal conductivity. The thermal conductivity coefficient is required to be higher than 1.0w /mK and the thickness is less than 100um.

### 清洁Clean

需要清洁的话，用干净的软碎布沾点酒精轻力擦除异物，不可以采用诸如丙酮之类的清洁剂以免可能造成腐蚀破坏。

If you need to clean, use a clean, soft cloth dipped in alcohol to gently remove foreign matter. Do not use a cleaner such as acetone to avoid possible corrosion damage.

### 电性注意事项Electrical precautions

1. LED 不允许反向驱动。

Led Reverse drive is not allowed

1. 限流措施是必要的，否则轻微的电压变化会导致较大的电流变化，可能造成 LED 失效。

Current limiting measures are necessary, otherwise slight voltage changes will lead to large current changes, which may lead to LED failure.

1. 在发光量满足要求的前提下，推荐采用低于额定电流的驱动电流，这样有利于提高产品的可靠性。

Under the premise that the luminous quantity meets the requirements, it is recommended to use the drive current lower than the rated current, which is conducive to improving the reliability of the product.

### 防静电措施anti-static precautions

LED 是静电敏感器件，在保存、使用过程中要采取防静电措施。 静电和电涌会导致产品特性发生改变，例如正向电压降低等，情况严重甚至会损毁产品。 所以对于整个工序（生产，测试，包装等）与 LED 直接接触的员工都要做好防止和消除静 电的措施。所有相关的设备和机器都应该正确接地。接地交流电阻小于 1.0 欧姆，工作台上需垫表面电阻 106-109 欧姆的桌垫。 在容易产生静电的环境和设备上，还必须安装离子风扇。作业过程中，操作员需使用防静电手环，防静电垫子，防静电工作服，工作鞋，手套，防静电容等。

LED is electrostatic sensitive devices, in the process of preservation, use to take anti-static measures.Static electricity and surge can lead to changes in product characteristics, such as forward voltage reduction, which can be serious and even damage the product.So for the whole process (production, testing, packaging, etc.) and LED direct contact staff should do a good job to prevent and eliminate electrostatic measures.All related equipment and machinery should be properly grounded.The grounding ac resistance is less than 1.0 ohm, the table mat with surface resistance of 106-109 ohm is needed on the work table.Ion fans must also be installed in electrostatic environments and equipment.During the operation, the operator should use anti-static bracelet, anti-static mat, anti-static overalls, working shoes, gloves, anti-static capacity.

**电烙铁焊接An electric soldering iron**

建议使用防静电电烙铁，尖端处温度不超过 350℃，每次焊锡时少于 3 秒。电烙铁的功率宜低于 60W。每焊完一次之后间隔 2 秒以上，分别焊好两个电极引脚。焊接时不可对透镜用力施压。LED如有问题一般都是从焊锡时开始出现。故必须按要求小心作业。

It is recommended to use anti-static electric soldering iron, the temperature at the tip does not exceed 350℃, less than 3 seconds for each soldering.The power of the soldering iron should be less than 60W.Weld two electrode pins more than 2 seconds after each welding.Do not force the lens during welding.Problems with leds usually begin when they are soldered.So you must work carefully as required.

 **SMT 回流焊说明Reflow instructions：**

### 注意事项matters need attention：

1. 回流焊只允许做一次。

Reflow soldering is only allowed once.

1. 回流焊过程中不要对灯体施加压力。

Do not apply pressure to the lamp body during reflow

1. 回流焊完成之后不要压挤散热板、不可压到胶体部分。

After reflow welding is completed, do not press the heat dissipation plate, do not press to the colloidal part.

1. 若有比较低熔点的锡膏，TP 可以适当降低。

If there is a lower melting point of solder paste, TP can be appropriately reduced.